

### Product Summary (@TA = +25°C)

Ррк	IFSM (A)	Vrwm (V)	PM(AV)
4600W	600	10 to 43	6W

# **Description and Applications**

Suitable to protect sensitive automotive circuits against surges defined in ISO7637-2 and against load-dump surge according to ISO16750-2.

Compliance with the following standards:

- ISO 16750-2, Pulse A and Pulse B
- ISO 7637-2 (Note 5)
  Pulse 1, Pulse 2a, Pulse 3a, Pulse 3b

### **Features and Benefits**

- 4600W Peak Pulse Power Dissipation
- High Current Capability
- Low Reverse Current
- Low Thermal Resistance
- Low Power Loss and High Efficiency
- Excellent High Temperature Stability
- Meets ISO7637-2 Surge Capability
- Meets ISO16750-2 Surge Specification
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DM6W10AQ-DM6W43AQ are suitable for automotive applications requiring specific change control; these parts are AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

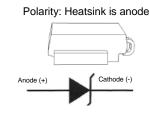
### Mechanical Data

- Package: DO-218
- Package Material: Molded Plastic.
  UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Lead-Free Plating (Matte Tin Finish). Solderable per MIL-STD-202, Method 208 (23)
- Polarity Indicator: Heatsink is Anode
- Weight: 2.74 grams (Approximate)

#### DO-218 (Type E)



Top View



Pin Information

### Ordering Information (Note 4)

Part Number	Qualification	Baakaga	Pac	Packing		
Part Number	Quantication	Package	Qty.	Carrier		
DM6WxxAQ-13	Automotive	DO-218 (Type E)	750	Tape & Reel		

\*x = Device Voltage, e.g., DM6W10AQ-13

1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

5. Not applicable to parts with stand-off voltage lower than the average battery voltage (13.5V).

Notes:



# **Marking Information**



M6WxxA = Product Type Marking Code (i.e. M6W10A for DM6W10AQ-13) );; = Manufacturers' Code Marking aa: Wafer source code y: Year (M = 2022) m: Month (1 - C) d: Date (1 - V)

cc: Lot serial number

Bar Denotes Cathode Pin, Circle Denotes Anode

Date Code Key

Year	2018		2022	2023	2024	2025	2026	2027	2028	2029	2030	2031
Code			М	Ν	0	Р	Q	R	S	Т	U	V
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	А	В	С
Date	1	2	3		9	10	11	12		29	30	31
Code	1	2	3		9	А	В	С		Т	U	V

# Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Peak Pulse Power Dissipation	10/1000µs Waveform	Ррк	4.600	
(Non Repetitive Current Pulse Derated above $T_A = +25^{\circ}C$ ) (Note 6)	10/10000µs Waveform		3,600	W
Peak Forward Surge Current, 8.3ms Single Half Sine-Wave Superimposed on Rated Load	I <sub>FSM</sub>	600	А	
Steady State Power Dissipation $@T_C = +25^{\circ}C$	PM(AV)	6.0	W	

## **Thermal Characteristics**

Characteristic	Symbol	Value	Unit
Typical Thermal Resistance, Junction to Case	Rejc	1.0	°C/W
Operating Temperature Range	TJ	-55 to +175	°C
Storage Temperature Range	T <sub>STG</sub>	-55 to +175	°C

Notes: 6. Valid provided that terminals are kept at ambient temperature.

7. Measured on 8.3ms single half sine-wave or equivalent square wave. Duty cycle = 4 pulses per minute maximum.



# Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

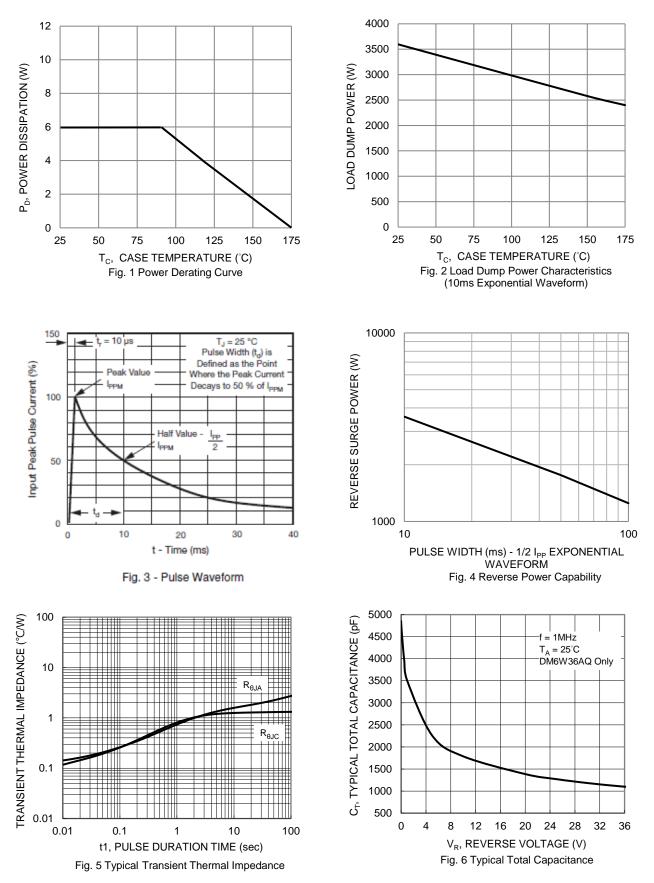
Part Number	Reverse Standoff Voltage	Vol	kdown tage r (Note 8)	Test Current	Max. Reverse Leakage @ V <sub>RWM</sub> (Note 10)	Max. Clamping Voltage @ Ipp	Max. Peak Pulse Current I <sub>pp</sub> at 10/1000µs (Note 9)	Maximum Leakage at V <sub>WM</sub> TJ = +175℃
	VRWM (V)	Min (V)	Max (V)	Iт (mA)	I <sub>R</sub> (μΑ)	Vc (V)	(A)	I <sub>D</sub> (μΑ)
DM6W10AQ	10	11.1	12.3	5	15	17.0	271	250
DM6W11AQ	11	12.2	13.5	5	10	18.2	253	150
DM6W12AQ	12	13.3	14.7	5	10	19.9	231	150
DM6W13AQ	13	14.4	15.9	5	10	21.5	214	150
DM6W14AQ	14	15.6	17.2	5	10	23.2	198	150
DM6W15AQ	15	16.7	18.5	5	10	24.4	189	150
DM6W16AQ	16	17.8	19.7	5	10	26.0	177	150
DM6W17AQ	17	18.9	20.9	5	10	27.6	167	150
DM6W18AQ	18	20.0	22.1	5	10	29.2	158	150
DM6W20AQ	20	22.2	24.5	5	10	32.4	142	150
DM6W22AQ	22	24.4	26.9	5	10	35.5	130	150
DM6W24AQ	24	26.7	29.5	5	10	38.9	118	150
DM6W26AQ	26	28.9	31.9	5	10	42.1	119	150
DM6W28AQ	28	31.1	34.4	5	10	45.4	101	150
DM6W30AQ	30	33.3	36.8	5	10	48.4	95	150
DM6W33AQ	33	36.7	40.6	5	10	53.3	86	150
DM6W36AQ	36	40.0	44.2	5	10	58.1	79	150
DM6W40AQ	40	44.4	49.1	5	10	64.5	71	150
DM6W43AQ	43	47.8	52.8	5	10	69.4	66	150

Notes:

8. V<sub>BR</sub> measured with I<sub>T</sub> current pulse = 10ms to 15ms.
 9. Refer to Figure 3 for the waveform.
 10. A short duration pulse test is used to minimize the self-heating effect.



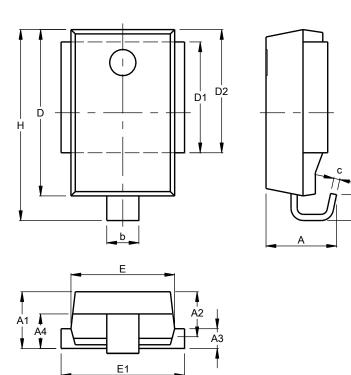
### DM6W10AQ-DM6W43AQ





## **Package Outline Dimensions**

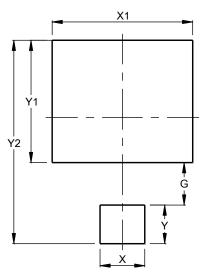
Please see http://www.diodes.com/package-outlines.html for the latest version.



DO-218 (Type E)						
Dim	Min Max Typ					
Α	4.70	5.70				
A1	4.70	5.25	5.00			
A2	3.45	4.26	3.95			
A3	1.70	2.50	2.00			
A4	2.58	3.55	3.10			
b	2.30	2.30 3.00				
С	0.45	0.90				
D	13.20	13.80	13.50			
D1	8.70	9.30	9.00			
D2	9.70	10.30	10.00			
ш	8.20	8.80	8.50			
E1	9.50	10.50				
Н	15.00	16.00	15.50			
L	1.50	2.50	2.00			
All	Dimensi	ons in	mm			

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
G	3.30
Х	3.50
X1	11.00
Y	3.00
Y1	9.50
Y2	15.80



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